

CIR-V4DESY3216G

DDR4 DIMM 3200MHz 16GB with ECC

Description

This specification defines the electrical and mechanical requirements for 288 pin, 1.2 V (VDD), Double Data Rate, Synchronous DRAM Dual In-Line Memory Modules (DDR4 SDRAM ECC U-DIMM). This DDR4 ECC U-DIMM is intended for use as main memory when installed in PCs, laptops and other systems.

Reference design examples are included which provide an initial basis for DDR4 ECC U-DIMM designs. Modifications to these reference designs may be required to meet all system timing, signal integrity and thermal requirements for DDR4-3200 support.

All DDR4 ECC U-DIMM implementations must use simulations and lab verification to ensure proper timing requirement and signal integrity in the design.

Specifications

Density	16GB
Pin Count	288pin
Type	Unbuffered
Dimensions	133.35mm x 31.25mm
ECC	with ECC
Component Config	1G x 8 bit
Data Rate	3200MHz
CAS Latency	22
Voltage	1.2V
PCB Layers	8
Operating Temp.(TCASE)	0°C~+95°C
Module Ranks	Dual Rank

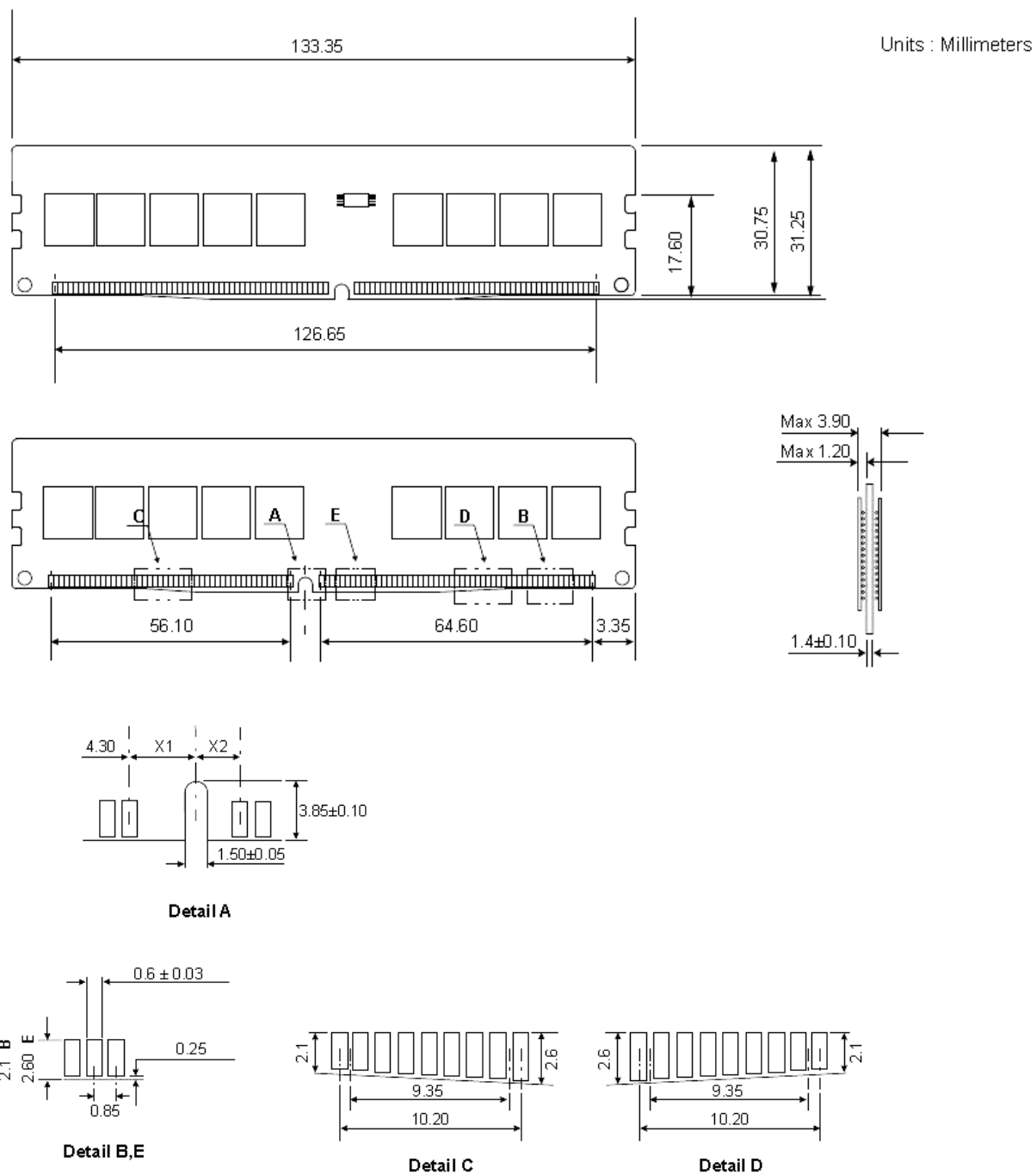
Features

- JEDEC Standard 288-pin Dual In-Line Memory Module
- VDD=VDDQ = 1.2V±0.06V (1.14V~1.26V)
- Programmable CAS Latency(posted CAS): 11,12,13,14,15,16,17,18,19,20,21,22
- Low-Power auto self-refresh (LPASR)
- SDRAMs have 16 internal banks for concurrent operation (4 Bank Group of 4banks each)
- Normal and Dynamic On-Die Termination for data, strobe and mask signals.
- Data bus inversion (DBI) for data bus
- Fixed burst chop (BC) of 4 and burst length (BL) of 8 via the MRS
- Selectable BC4 or BL8 on-the fly (OTF)
- ECC Function
- On-die VREFDQ generation and Calibration
- RoHs and Halogen free

Speed Grade

Frequency Grade	Data Transfer Rate	CAS Latency Support												CL-tRCD-tRP
		CL11	CL12	CL13	CL14	CL15	CL16	CL17	CL18	CL19	CL20	CL21	CL22	
DDR4-3200	PC4-25600	1600	1600	1866	1866	2133	2133	2400	2400	2666	2666	2933	3200	22-22-22

Package Dimensions



Tolerances : $\pm 0.25\text{mm}$ unless otherwise specified